



UT136FF/FG

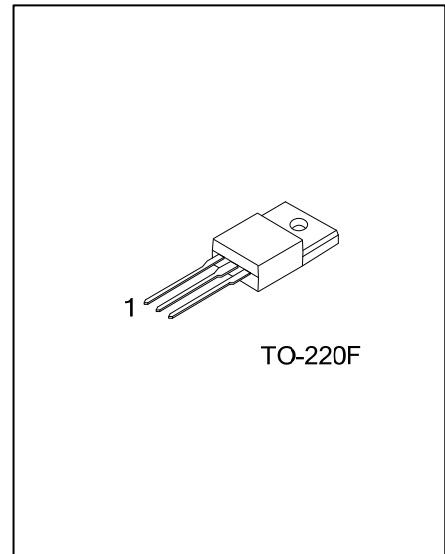
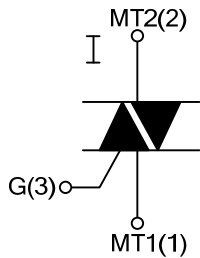
TRIAC

TRIAC

■ **DESCRIPTION**

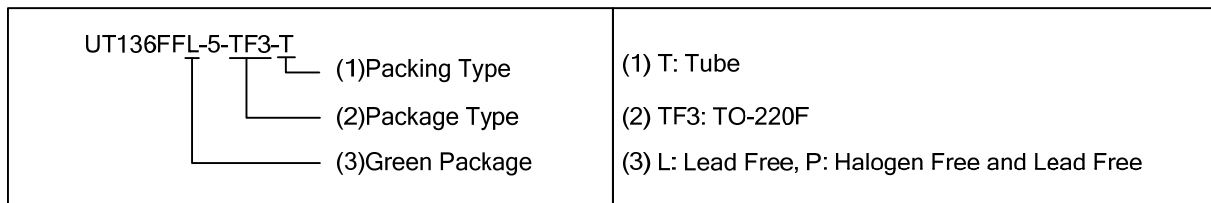
Glass passivated triac in a full pack plastic envelope, intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

■ **SYMBOL**

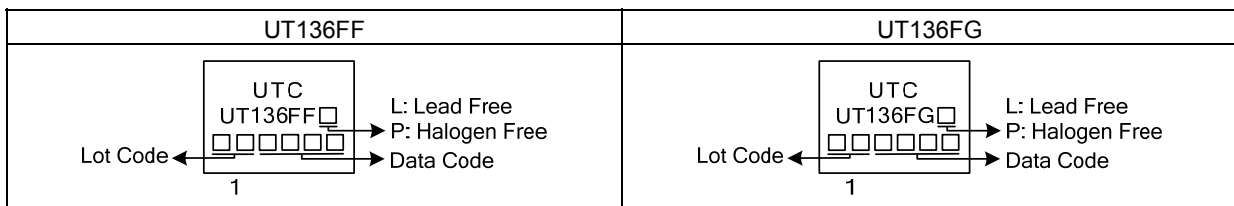


■ **ORDERING INFORMATION**

Ordering Number		Package	Pin Description			Packing
Lead Free	Halogen Free		1	2	3	
UT136FFL-5-TF3-R	UT136FFP-5-TF3-R	TO-220F	MT1	MT2	G	Tube
UT136FFL-6-TF3-R	UT136FFP-6-TF3-R	TO-220F	MT1	MT2	G	Tube
UT136FFL-8-TF3-R	UT136FFP-8-TF3-R	TO-220F	MT1	MT2	G	Tube
UT136FGL-5-TF3-R	UT136FGP-5-TF3-R	TO-220F	MT1	MT2	G	Tube
UT136FGL-6-TF3-R	UT136FGP-6-TF3-R	TO-220F	MT1	MT2	G	Tube
UT136FGL-8-TF3-R	UT136FGP-8-TF3-R	TO-220F	MT1	MT2	G	Tube



■ **MARKING**



■ ABSOLUTE MAXIMUM RATING

PARAMETER		SYMBOL	RATINGS	UNIT
Repetitive Peak Off-State Voltages	UT136FF/FG-5	V_{DRM}	500(Note2)	V
	UT136FF/FG-6		600(Note2)	
	UT136FF/FG-8		800	
RMS On-state Current Full sine wave, $T_{HS} \leq 92^{\circ}C$		$I_{T(RMS)}$	4	A
Non-Repetitive Peak. On-State Current Full sine wave, $T_J = 125^{\circ}C$ prior to surge, with reapplied $V_{DRM(MAX)}$	$t = 20$ ms	I_{TSM}	25	A
	$t = 16.7$ ms		27	
I^2t For Fusing ($t = 10$ ms)		I^2t	3.1	A^2s
Repetitive Rate of Rise of On-state Current after Triggering $I_{TM} = 6$ A, $I_G = 0.2$ A, $dI_G/dt = 0.2A/\mu s$	T2 + G+	di_T/dt	50	A/ μs
	T2 + G-		50	
	T2 - G-		50	
	T2 - G+		10	
Peak Gate Voltage		V_{GM}	5	V
Peak Gate Current		I_{GM}	2	A
Peak Gate Power		P_{GM}	5	W
Average Gate Power (Over any 20ms period)		$P_{G(AV)}$	0.5	W
Operating Junction Temperature		T_J	125	$^{\circ}C$
Storage Temperature		T_{STG}	-40 ~ +150	$^{\circ}C$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 3A/ μs .

■ THERMAL DATA

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Thermal Resistance, Junction to Ambient (In free air)	θ_{JA}		55		K/W

■ ISOLATION LIMITING VALUE & CHARACTERISTIC ($T_{HS} = 25^{\circ}C$, unless otherwise specified)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Repetitive peak voltage from all three terminals to external heatsink (R.H. $\leq 65\%$, clean and dustfree)	V_{ISOL}			1500	V
Capacitance from MT2 to external heatsink ($f = 1$ MHz)	C_{ISOL}		12		pF

■ STATIC CHARACTERISTICS ($T_J = 25^{\circ}C$, unless otherwise specified)

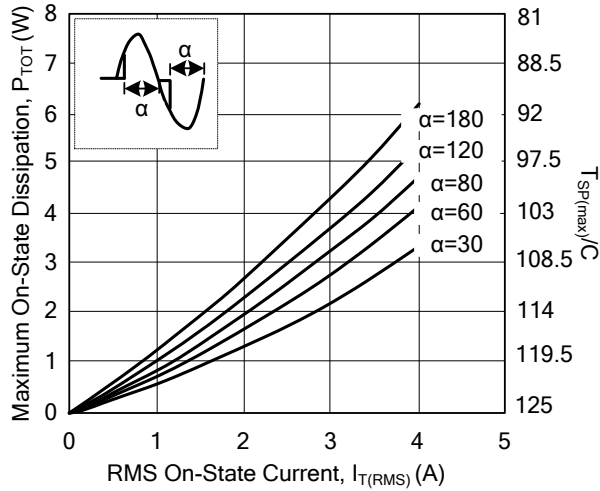
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX		UNIT
					UT136FF	UT136FG	
Gate Trigger Current	I_{GT}	$V_D = 12$ V, $I_T = 0.1$ A	T2 + G+	5	25	50	mA
			T2 + G-	8	25	50	mA
			T2 - G-	11	25	50	mA
			T2 - G+	30	70	100	mA
Latching Current	I_L	$V_D = 12$ V, $I_{GT} = 0.1$ A	T2 + G+	7	20	30	mA
			T2 + G-	16	30	45	mA
			T2 - G-	5	20	30	mA
			T2 - G+	7	30	45	mA
Holding Current	I_H	$V_D = 12$ V, $I_{GT} = 0.1$ A		5	15	30	mA
On-State Voltage	V_T	$I_T = 5$ A		1.4	1.70		V
Gate Trigger Voltage	V_{GT}	$V_D = 12$ V, $I_T = 0.1$ A		0.7	1.5		V
		$V_D = 400$ V, $I_T = 0.1$ A, $T_J = 125^{\circ}C$	0.25	0.4			V
Off-State Leakage Current	I_D	$V_D = V_{DRM(MAX)}$, $T_J = 125^{\circ}C$		0.1	0.5		mA

■ DYNAMIC CHARACTERISTICS (T_J=25°C, unless otherwise specified)

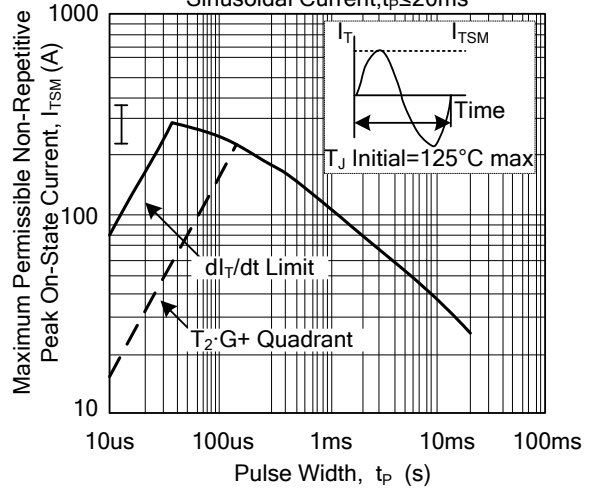
PARAMETER	SYMBOL	TEST CONDITIONS	MIN		TYP	MAX	UNIT
			UT136FF	UT136FG			
Critical Rate of Rise of Off-State Voltage	dV _D /dt	V _{DM} = 67% V _{DRM(MAX)} , T _J =125°C, exponential waveform, gate open circuit	50	200	250		V/μs
Critical Rate of Change of Commutating Voltage	dV _{COM} /dt	V _{DM} =400V, T _J =95°C, I _{T(RMS)} =4A, dI _{COM} /dt=1.8A/ms, gate open circuit		10	50		V/μs
Gate Controlled Turn-On Time	t _{GT}	I _{TM} =6A, V _D = V _{DRM(MAX)} , I _G =0.1A, dI _G /dt=5A/μs			2		μs

TYPICAL CHARACTERISTICS

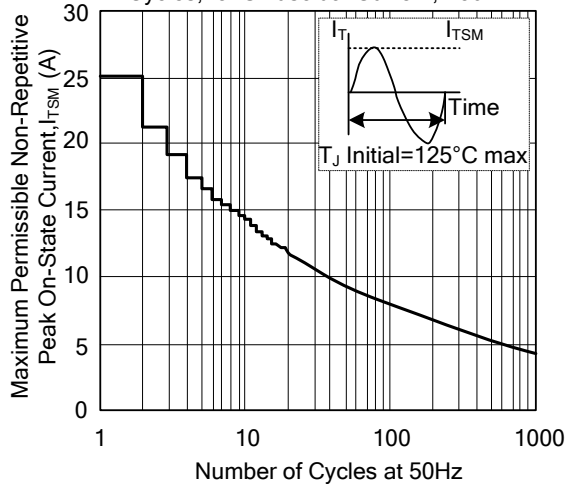
Maximum On-State Dissipation, P_{TOT} vs RMS On-State Current, $I_{T(RMS)}$, Where α =Conduction Angle



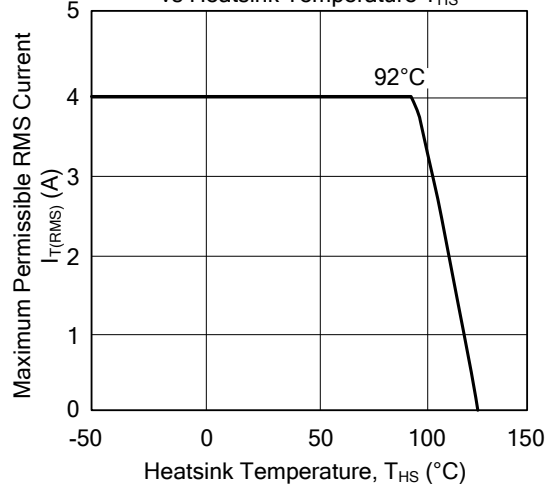
Maximum Permissible Non-Repetitive Peak On-State Current, I_{TSM} , vs Pulse Width t_p , for Sinusoidal Current, $t_p \leq 20ms$



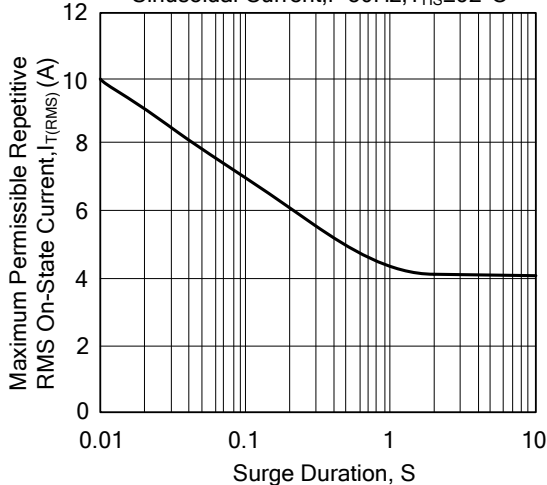
Maximum Permissible Non-Repetitive Peak On-State Current, I_{TSM} , vs Number of Cycles, for Sinusoidal Current, $f=50Hz$



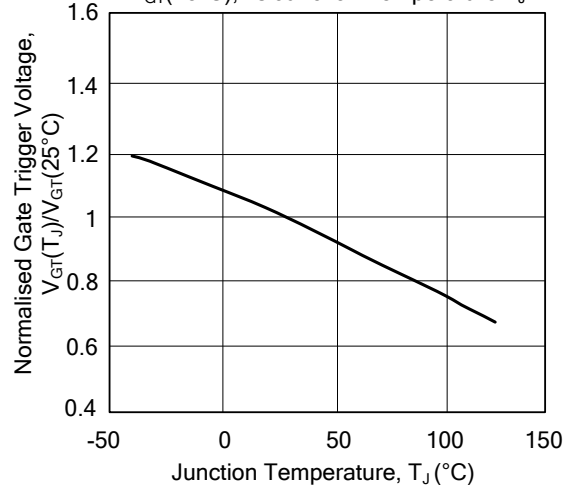
Maximum Permissible RMS Current $I_{T(RMS)}$ vs Heatsink Temperature T_{HS}



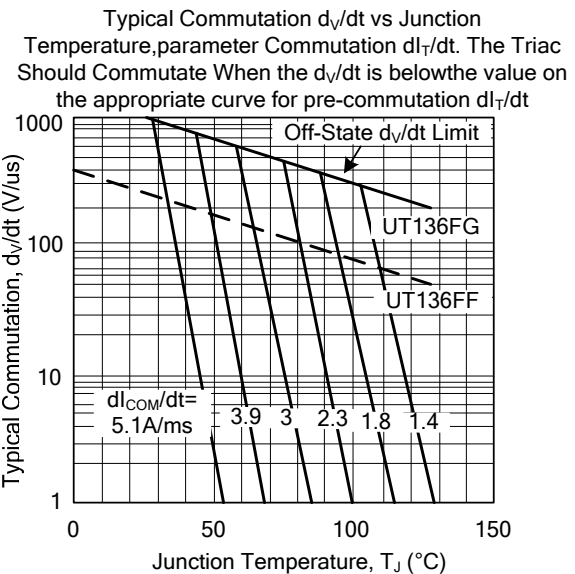
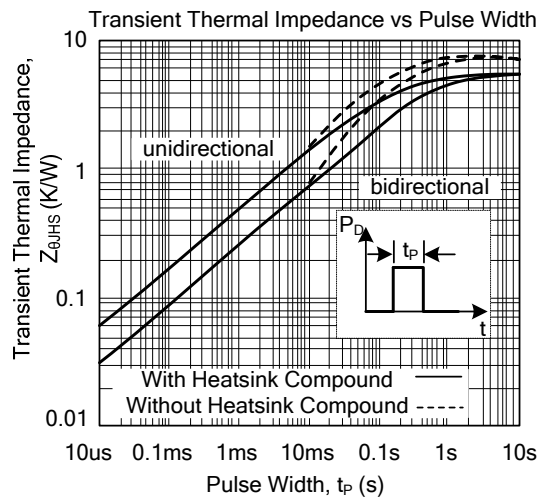
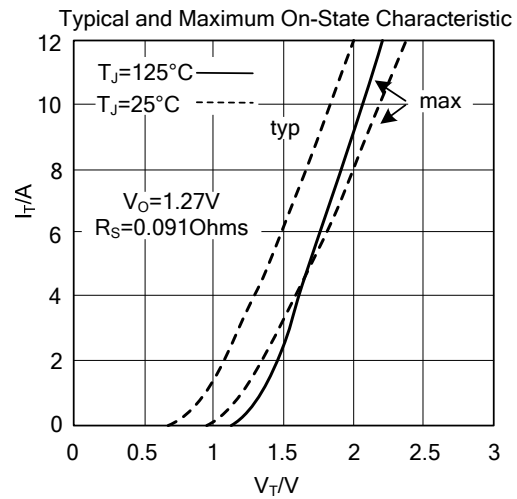
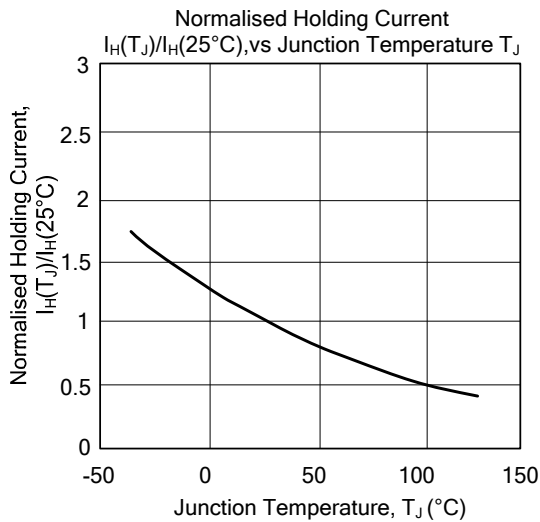
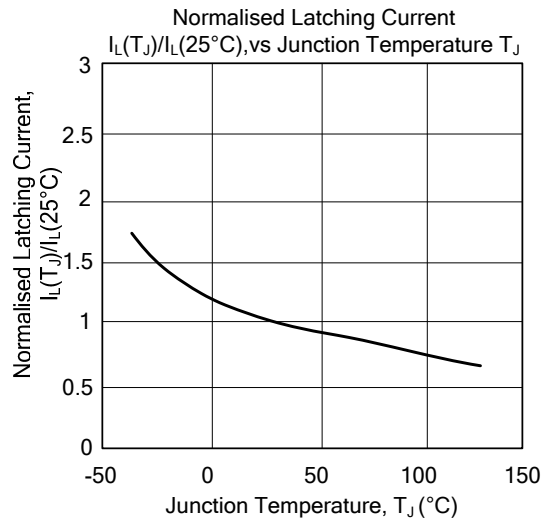
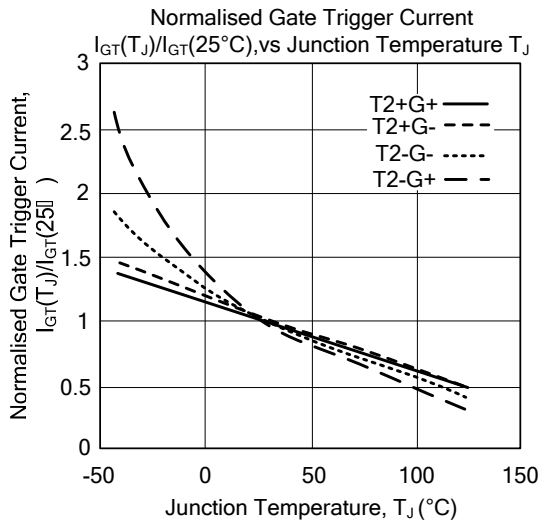
Maximum Permissible Repetitive RMS On-State Current, $I_{T(RMS)}$, vs Surge Duration, for Sinusoidal Current, $f=50Hz, T_{HS} \leq 92^\circ C$



Normalised Gate Trigger Voltage $V_{GT}(T_J)/V_{GT}(25^\circ C)$, vs Junction Temperature T_J



TYPICAL CHARACTERISTICS(Cont.)



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